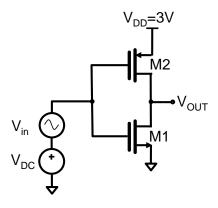
1) Assume that M1 and M2 are in the saturation region and that  $V_{DC}$  is set to produce a DC  $V_{OUT}$  which is optimal for maximum headroom and output voltage swing. Also, assume that the drain currents of M1 and M2 are  $I_D = 0.5$ mA (Total: 25 points) Device characteristics:  $\mu_n C_{ox} = 4mA/V^2$ ,  $\mu_p C_{ox} = 2mA/V^2$  (W/L)<sub>M1</sub> = (10 $\mu$ m/0.5 $\mu$ m), and (W/L)<sub>M2</sub> = (20 $\mu$ m/0.5 $\mu$ m),  $\lambda_p = \lambda_n = 0.1 V^{-1}$  and  $V_{THn} = 0.7 V$  and  $V_{THp} = 0.8 V$ .



- a) What is the small-signal gain  $A_v = \frac{v_{OUT}}{v_{in}}$ ? (15 points)
- b) What is the optimal DC value of  $V_{OUT}$  to produce a maximum peak-to-peak output swing? This question is **not** asking you to compute  $V_{OUT}$  DC using the drain current equations for M1 and M2, but rather find the optimal VOUT DC given the ( $V_{GS}$ - $V_{TH}$ ) of M1 and M2. (5 points) What is the corresponding peak output swing? (5 points)

2) For the below single-transistor amplifier, both an ideal DC current source and ideal AC current are applied to the input. It is fair to assume  $M_1$  is in the saturation region and behaves like a "square law" device. Find the DC value of V<sub>OUT</sub> (5 points) – note: ignore the body affect ( $\lambda$ =0) to make the calculation of the DC bias easier. Next, draw the small signal circuit for this amplifier and derive an expression for the smallsignal AC transresistance  $(v_{out}/i_{in})$ , state any assumptions made to get your answer. Lastly, compute the value of the transresistance. (20 points) Note: for the AC-SS analysis you cannot ignore the body effect – e.g.  $\lambda$ =0.01V<sup>-1</sup> Device characteristics:  $\mu_n C_{ox} = 5mA/V^2$ ,  $(W/L)_{M1} = (10\mu m/1\mu m)$ ,  $\lambda = 0.01 V^{-1}$  and

 $V_t = 0.7V$ .

